Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.300 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.125 inches

End Application:

Ticonderoga class cg (47); radar, series an/sps-4 (v); los angeles class ssn (688); sturgeon class ssn (637); landing craft air cushion (lcac); virginia class cg (41); austi ship class lpd-4 amphibious trasnport docks; tactical data system, an/uya-4(v); communications, lha; sirius class t-afs 8

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak

Current Rating Per Characteristic:

0.20 amperes forward current, average

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Special Features:

Item must comply with rqmt of desc production standard no. L00918; weapon system essential

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0